

Data sheet acquired from Harris Semiconductor SCHS048

# CMOS Liquid-Crystal Display Drivers

High-Voltage Types (20-Volt Rating)

CD4054B - 4-Segment Display Driver

CD4055B — BCD to 7-Segment Decoder/Driver with "Display-Frequency" Output

CD4056B — BCD to 7-Segment Decoder/Driver with Strobed-Latch Function

single-digit BCD-to-7-segment decoder/driver circuits that provide level-shifting functions on the chip. This feature permits the BCD input-signal swings (VDD to VSS) to be the same as or different from the 7-segment output-signal swings (VDD to VEE). For example, the BCD input-signal swings (VDD to VSS) may be as small as 0 to -3 V, whereas the output-display drive-signal swing (VDD to VEE) may be as large as from 0 to -15V. If VDD to VEE exceeds 15 V, VDD to VSS should be at least 4V (0 to -4V).

The 7-segment outputs are controlled by the DISPLAY-FREQUENCY (DF) input which causes the selected segment outputs to be low, high, or a square-wave output (for liquid-crystal displays). When the DF input is low the output segments will be high when selected by the BCD inputs. When the DF input is high, the output segments will be low when selected by the BCD inputs. When a square-wave is present at the DF input, the selected segments will have a square-wave output that is 180° out of phase with the DF input. Those segments which are not selected will have a squarewave output that is in phase with the input. DF square-wave repetition rates for liquidcrystal displays usually range from 30 Hz (well above flicker rate) to 200 Hz (well below the upper limit of the liquid-crystal frequency response). The CD4055B provides a level-shifted high-amplitude DF output which is required for driving the common electrode in liquid-crystal displays. The CD4056B provides a strobed-latch function at the BCD inputs. Decoding of all input combinations on the CD4055B and CD4056B provides displays of 0 to 9 as well as L, P, H, A, -, and a blank position.

The CD4054B provides level shifting similar to the CD4055B and CD4056B independently strobed latches, and common DF control on 4 signal lines. The CD4054B is intended to provide drive-signal compatibility with the CD4055B and CD4056B 7-segment decoder types for the decimal point, colon, polarity, and similar display lines. A level-shifted high-amplitude DF output can be obtained from any CD4054B output line by connect-

# CD4054B, CD4055B, CD4056B Types

#### Features:

- Operation of liquid crystals with CMOS circuits provides ultra-low-power displays
- Equivalent ac output drive for liquidcrystal displays — no external capacitor required
- Voltage doubling across display, e.g.
   VDD VEE = 18 V results in effective
   36 V p-p drive across selected display segments
- Low- or high-output level dc drive for other types of displays
- On-chip logic-level conversion for different input- and output-level swings
- Full decoding of all input combinations:
   0-9, L, H, P, A,-, and blank positions
- Strobed-latch function—CD4054B Series and CD4056B Series
- DISPLAY-FREQUENCY (DF) output for liquid-crystal common-line drive signal— CD4055B Series (CD4054B Series also: see introductory text)
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):

1 V at V<sub>DD</sub> = 5 V 2 V at V<sub>DD</sub> = 10 V 2.5 V at V<sub>DD</sub> = 15 V

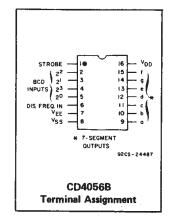
5-V, 10-V, and 15-V parametric ratings

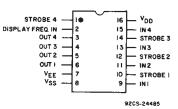
### **Applications**

- General-purpose displays
- Calculators and meters
- Wall and table clocks
- Industrial control panels
- Portable lab instruments
- Panel meters
- Auto dashboard displays
- Appliance control panels

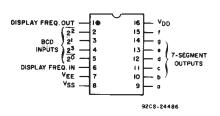
ing the corresponding input and strobe lines to a low and high level, respectively and applying a square wave to DF<sub>IN</sub>. The CD4054B may also be utilized for logic-level "up conversion" or "down conversion". For example, input-signal swings (VDD to VSS) from +5 to 0 V can be converted to outputsignal swings (VDD to VEE) of +5 to -5 V. The level-shifted function on all three types permits the use of different input- and output-signal swings. The input swings from a low level of VSS to a high level of VDD while the output swings from a low level of VEE to the same high level of VDD. Thus, the input and output swings can be selected independently of each other over a 3-to-18 V range. VSS may be connected to VEE when no level-shift function is required.

For the CD4054B and CD4056B, data are





CD40548 Terminal Assignment



CD4055B Terminal Assignment

transferred from input to output by placing a high voltage level at the strobe input. A low voltage level at the strobe input latches the data input and the corresponding output segments remain selected (or non-selected) while the strobe is low.

Whenever the level-shifting function is required, the CD4055B can be used by itself to drive a liquid-crystal display (Fig.16 and Fig.20). The CD4056B, however, must be used together with a CD4054B to provide the common DF output (Fig.19). The capability of extending the voltage swing on the negative end (this voltage cannot be extended on the positive end) can be used to advantage in the setup of Fig.18. Fig.17 is common to all three types.

The CD4054B-, CD4055B-, and CD4056B-series types are available in 16-lead ceramic dual-in-line packages (D and F suffixes), 16-lead plastic packages (E suffix), and in chip form (H suffix).

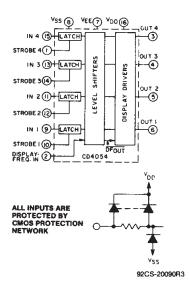


Fig.1 - CD4054B functional diagram.

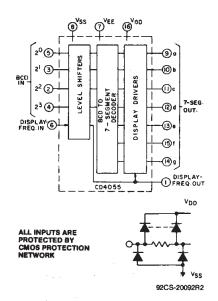


Fig.2 - CD4055B functional diagram.

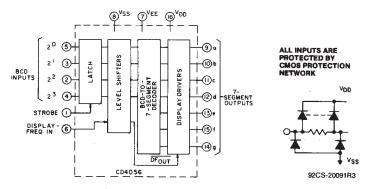


Fig.3 - CD4056B functional diagram.

### **CD4054B TRUTH TABLE**

DF	IN	ST	OUT
0	0	1	0
1	0	1	1
0	1	1	1
1	1	1	0
Х	Х	0	•

X = Don't Care.

\*Depends upon the input mode previously applied when ST = 1.

#### TRUTH TABLE FOR CD4055B and CD4056B

INPUT CODE			OUTPUT STATE								DISPLAY CHARAC-		
<b>2</b> <sup>3</sup>	22	21	20		а	ь	С	d	е	f	g		TER
0	0	0	0		1	1	1	1	1	1	0	I	1_1
0	0	0	1		0	1	1	0	0	0	0	Π	
0	0	1	0		1	1	0	1	1	0	1		
0	0	1	1		1	1	1	1	0	0	1		
0	1	0	0		0	1	1	0	0	1	1	ľ	1-
0	1	0	1		1	0	1	1	0	1	1	Π	<u> </u>
0	1	1	0		1	0	1	1	1	1	1		E
0	1	1	1		1	1	1	0	0	0	0	ĺ	
1	0	0	0		1	1	1	1	1	1	1	Ī	
1	0	0	1		1	1	1	1	0	1	1	Ī	
1	0	1	0		0	0	0	1	1	1	0		_
1	0	1	1		0	1	1	0	1	1	1		;—;
1	1	0	0		1	1	0	0	1	1	1	ĺ	-  -
_1	1	0	1		1	1	1	0	1	1	1		<u> </u>
1	1	1	0		0	0	0	0	0	0	1		_
1	1	1	1		0	0	0	0	0	0	0		BLANK

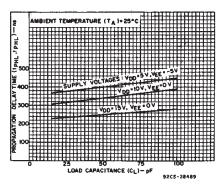


Fig.4 — Typical propagation delay time vs. load capacitance for CD4054B.

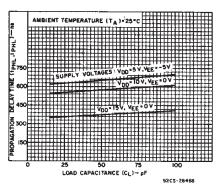


Fig.5 — Typical propagation delay time vs. load capacitance for CD4055 and CD4056B.

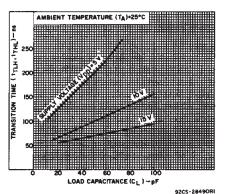


Fig.6 - Typical transition time vs, load capacitance.

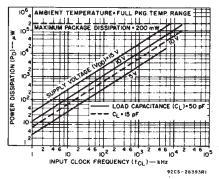


Fig.7 – Typical input clock frequency vs. power dissipation.

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)0.5V to +20V	,
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to V <sub>DD</sub> +0.5V	f
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T <sub>A</sub> = -55°C to +100°C	,
For T <sub>A</sub> = +100°C to +125°C	1
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	,
OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )55°C to +125°C	
STORAGE TEMPERATURE RANGE (T <sub>stg</sub> )65°C to +150°C	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max+265°C	;

## STATIC ELECTRICAL CHARACTERISTICS

			NDIT	ions									
Characteristic	VEE		1		VDD								Units
	(V)	(V)	(V)	(V)	(V)				l _	+25°C			]
	—	<u> </u>	<u> </u>	ــــــ		-55°	-40°	+	+1250	Min.	Typ.	Max.	
Quiescent Device	5	0	L.		5		5	150	150		0.04	5	μΑ
Current, IDD	0	0			10	_	10	300	300		0.04	10	1
MAX.	0	0	-		15	<del></del>	20	600	600	_	0.04	20	]
ļ	0	0	<u> </u>		20	1 1	00	3000	3000	_	0.08	100	
Output Voltage:		_	Į							!			
	0	0	<u> </u>	0,5	5			.05			0	0.05	
Low Level, VOL	0	0		0,10	10			.05			0	0.05	
MAX	0	0		0,15	15		0.05				0	0.05	] <sub>v</sub>
	0	0		0,5	5			.95		4.95	5	-	]
High Level, VOH	0	0		0,10	10	9.95				9.95	10		
IVIIN.	MIN. 0 0 0,15 15 14.95			14.95	15		1 1						
Input Low	0	0	0.5, 4.5		5		1	.5		_	_	1.5	
Voltage, V <sub>II</sub> MAX.	0	0	1,9		10			3			-	3	
ATE MAY	0	0 1	.5,13.	5	15		-	4			<del> </del>	4	
Input High	-5	0	0.5,4.5	5	5		3	3.5		3.5	<del></del>		٧
Voltage,	0	0	1,9		10			7		7	+		1
VIH MIN.	0	0 1	.5,13.5		15			<u>:</u> I 1		11	<del>  </del>		
Output Low (Sink)	-5	0	-4.5		5	0.98	0.92	0.67	0.55	0.8	1.6		
Current, IOL	0	0	0.5		10	0.98	0.92	0.67	0.55	0.8	1.6	_	
	0	0	1.5		15	3.6	3.4	2.4	2	2.9	5.8		
Output High	<b>-</b> 5	0	4.5		5	-0.6	0.55	0.35	0.3	0.45	~0.9		mA
(Source)	0	0	9.5		10	-0.6	0.55	0.35	-0.3	-0.45	-0.9		
Current, IOH	0	0	13.5		15	-1.9	-1.8	-1.2	-1.1	~ 1.5	-3	-	
Input Current,	0	0	_	0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μΑ

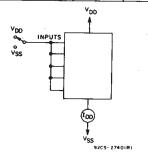


Fig. 11 - Quiescent-device-current test circuit.

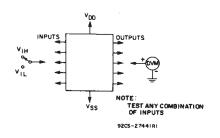


Fig. 12 - Input-voltage test circuit.

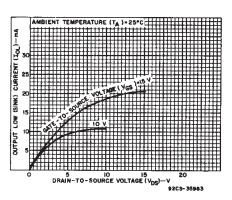


Fig.8 — Typical n-channel output low (sink) current characteristics.

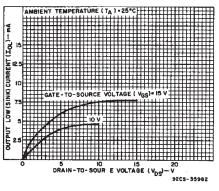


Fig.9 - Minimum n-channel output low (sink) current characteristics.

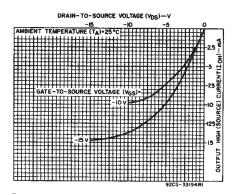


Fig. 10 - Typical p-channel output high (source) current characteristics.

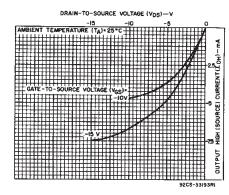


Fig. 13 — Minimum p-channel output high (source) current characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at  $T_A = 25^{\circ}$ C,  $C_L = 50$  pF, Input  $t_f$ ,  $t_f = 20$  ns,  $R_1 = 200$  k $\Omega$ 

	CONDITIONS			Δ					
CHARACTERISTIC	VEE	VSS (V)	V <sub>DD</sub> (V)	CD4054		CKAGE 1 CD4055	UNITS		
	(V)			Тур.	Max.	Тур.	Max.		
Propagation Delay Time,	<b>-</b> 5	0	5	400	800	650	1300		
tPHL, tPLH	0	0	10	340	680	575	1150	ns	
(Any Input to Any Output)	0 -	0	15	250	500	375	750		
Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>	-5	0	5	100	200	100	200		
	0	0	10	100	200	100	200	ns	
(Any Output)	0	0	15	75	150	75	150		
Minimum Data Setup	5	0	5	110	220	110	220		
Time, ts*	0	0	10	50	100	50	100	ns	
Time, ts			15	35	70	35	70		
Minimum Strobe Pulse	-5	0.	5	110	220	110	220		
1 7 7	0	0	10	50	100	50	100	ns	
Width, t <sub>W</sub> *	0	0	15	35	70	35	70		
Input Capacitance, CIN (Any Input)	_	_		5	7.5	5	7.5	рF	

<sup>\*</sup> CD4054 and CD4056 only.

### RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}$ C (Unless otherwise specified)

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CUADACTERISTIC	VEE	VSS	V <sub>DD</sub>	LIM			
CHARACTERISTIC	(V)	(V)	(V)	Min.	Max.	UNITS	
Supply Voltage Range: (At TA = Full Package Temperature Range)				3	18	٧	
	-5	0	5	220		ns	
Setup Time (t <sub>s</sub> )●	0	0	10	100			
•	0	0	15	70	_	]	
	-5	0	5	220	_	ļ	
Strobe Pulse Width (tw)	0	0	10	100	-	ns	
••	0	0	15	70		]	

<sup>•</sup> For CD4054 and CD4056 only.

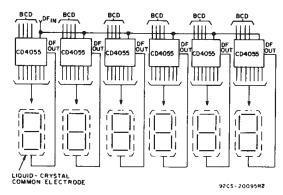


Fig. 16 - Clock display:  $V_{DD} = 0$  V,  $V_{SS} = -5$  V,  $V_{EE} = -15$  V,  $DF_{IN} = 30$  Hz square wave.

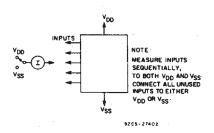


Fig. 14 - Input-current test circuit.

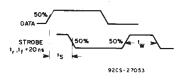
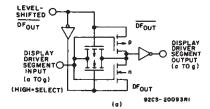


Fig. 15 — Data setup time and strobe pulse duration.



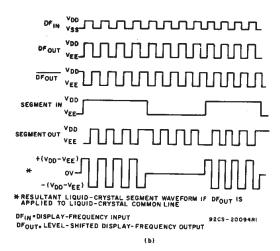


Fig. 17 - Display-driver circuit for one segment line and waveforms,

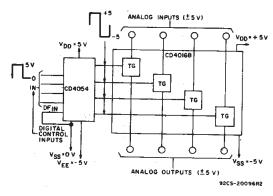


Fig. 18 - Digital (0 to +5 V) to bidirectional analog control (+5 to -5 V) level shifter.

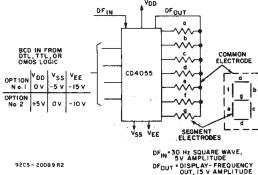


Fig.20 - Single-digit liquid-crystal display.

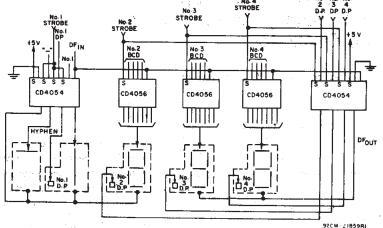


Fig. 19 — Typical 3%-digit liquid-crystal display: V<sub>DD</sub> = +5 V, V<sub>SS</sub> = 0 V, V<sub>EE</sub> = -10 V, DF<sub>IN</sub> = 30 Hz square wave.

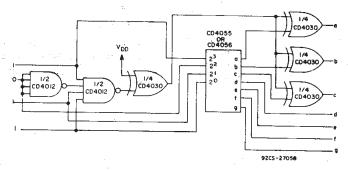


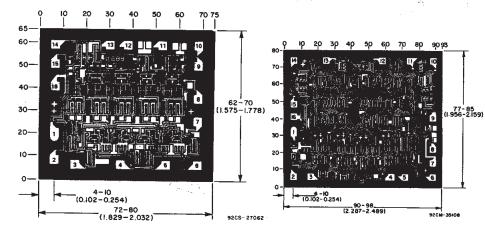
Fig.21 - Conversion of "H" display to "F" display.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10<sup>-3</sup> inch).

In addition to the letters L, H, P, and A (See the truth table), five other letters can be displayed through the use of simple logic circuits preceding and following the CD4055B or CD4056B devices. Fig.21 is an example of a circuit that converts an "H" display (code 1011) to an "F" display. One condition that must be met is that VEE=VSS. If VEE≠VSS, the CD4054B must be used to level shift in the appropriate places.

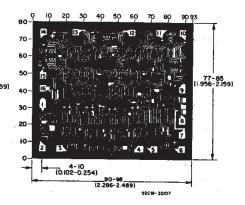
In a similar manner the letters C, E, J, and U can be displayed. These circuits can also be used to drive LED displays provided the exclusive-OR gates have sufficient output-current drive.

The letters B, D, G, I, O, and S may be represented by the codes for numbers 8, 0, 6, 1, 0, and 5, respectively, when there is preknowledge that only letters are to be displayed.



Dimensions and pad layout for CD4054BH.

Dimensions and pad layout for CD40558H



Dimensions and pad layout for CD4056BH

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